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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/707,407	12/11/2003	Abdelaziz Ikhlef	GEMS8081.201	1406
27061 75	590 11/10/2005		EXAMINER	
ZIOLKOWSKI PATENT SOLUTIONS GROUP, SC (GEMS)			KAO, CHIH CHENG G	
14135 NORTH CEDARBURG ROAD MEQUON, WI 53097			ART UNIT	PAPER NUMBER
MEQUON, W	1 33071		2882	
	•		DATE MAILED: 11/10/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/707,407	IKHLEF ET AL.			
Office Action Summary	Examiner	Art Unit			
	Chih-Cheng Glen Kao	2882			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.  after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a rep  - If NO period for reply is specified above, the maximum statutory period  - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be timely within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 26 A	August 2005.				
,	This action is <b>FINAL</b> . 2b) ☐ This action is non-final.				
3) Since this application is in condition for allowa	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims					
<ul> <li>4)  Claim(s) 1-9,12-15 and 18-25 is/are pending is 4a) Of the above claim(s) is/are withdra</li> <li>5)  Claim(s) is/are allowed.</li> <li>6)  Claim(s) 1-9,12-15 and 18-25 is/are rejected.</li> <li>7)  Claim(s) is/are objected to.</li> <li>8)  Claim(s) are subject to restriction and/or</li> </ul>	wn from consideration.				
Application Papers					
9) ☐ The specification is objected to by the Examine 10) ☒ The drawing(s) filed on 11 December 2003 is/a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Examine 11.	are: a) accepted or b) objected if the drawing(s) is objected if the drawing(s) is objected or b)	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	ts have been received.  ts have been received in Application of the control of th	on No ed in this National Stage			
Attachment(s)  1) Notice of References Cited (PTO-892)	4) Interview Summary	•			
<ul> <li>2) Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)</li> <li>Paper No(s)/Mail Date</li> </ul>	Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ate atent Application (PTO-152)			

#### **DETAILED ACTION**

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 1. Claims 1-5, 7-9, 12-14, 20-22, 24, and 25 are rejected under 35 U.S.C. 102(b) as being anticipated by Possin et al. (US Patent 5430298).
- Regarding claim 1, Possin et al. discloses an apparatus comprising a scintillator array having a plurality of scintillators (fig. 1, #112) arranged along a first plane, a photodiode array having a plurality of photodiodes (fig. 1, #124) arranged along a second plane different from the first plane and parallel to the first plane, and configured to detect illumination of the scintillator array (fig. 1, #112), the first plane and the second plane orthogonal to a direction of x-ray (col. 1, line 15) incidence on the scintillator array (fig. 1, #112), and an optical mask (fig. 1, #180) arranged along a third plane parallel to the first and the second planes, and disposed between the scintillator array (fig. 1, #112) and the photodiode array (fig. 1, #124), the optical mask (fig. 1, #180) configured to reduce optical transference between a scintillator and a neighboring photodiode (title).

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- 3. Regarding claims 2 and 3, Possin et al. further discloses wherein the optical mask includes a grid of intersecting optical inhibitor elements (fig. 1, #180) dimensionally equivalent to the scintillator array (fig. 1, #112) and the photodiode array (fig. 1, #124).
- 4. Regarding claim 4, Possin et al. further discloses wherein the optical mask is defined by a plurality of parallel optical inhibitor elements (fig. 1, #180) extending traversely along a width of the photodiode array (fig. 1, #124).
- 5. Regarding claim 5, Possin et al. further discloses wherein the optical mask is formed of optical absorbing material (col. 5, lines 26-28).
- 6. Regarding claim 7, Possin et al. further discloses wherein each scintillator (fig. 1, #112) / photodiode (fig. 1, #124) combination defines a detector cell and wherein the optical mask (fig. 1, #180) is configured to reduce cross-talk between adjacent cells (title).
- Regarding claim 8, Possin et al. discloses an apparatus comprising a first and a second scintillator (fig. 1, #112) positioned adjacently to one another and distanced from one another by a given width, a first photodiode (fig. 1, #124) operationally aligned to detect illumination of the first scintillator (fig. 1, #112) and a second photodiode (fig. 1, #124) operationally aligned to detect illumination of the second scintillator (fig. 1, #112), and at least one mask element (fig. 1, #180) of optically absorbing material (col. 5, lines 26-28) disposed in a plane disposed between the first and second scintillators (fig. 1, #112) and the first and the second photodiodes (fig. 1,

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#124) to reduce optical transference between the first scintillator and the second photodiode and the second scintillator and the first photodiode (title), the at least one mask element (fig. 1, #180) having a width that exceeds the given width separating the first and the second scintillators (fig. 1, #112) from one another.

- 8. Regarding claim 9, Possin et al. further discloses wherein the first and the second scintillators (fig. 1, #112) are spaced from one another by a lateral gap (fig. 1, #115).
- 9. Regarding claim 12, Possin et al. further discloses wherein each scintillator (fig. 1, #112) is spaced from its corresponding photodiode (fig. 1, #124) by a vertical gap (fig. 1, #170).
- 10. Regarding claim 13, Possin et al. further discloses wherein each mask element (fig. 1, #180) has a thickness at least equal to a height of the vertical gap (fig. 1, #170).
- Regarding claim 20, Possin et al. discloses a method comprising the steps of providing a cellular arrangement of scintillators (fig. 1, #112), providing a cellular arrangement of photodiodes (fig. 1, #124), each photodiode (fig. 1, #124) configured to detect illumination of a corresponding scintillator (fig. 1, #112), providing an optical cross-talk mask (fig. 1, #180), and arranging the cellular arrangement of scintillators (fig. 1, #112), the cellular arrangement of photodiodes (fig. 1, #124), and the optical cross-talk mask (fig. 1, #180) in a multi-planar stack wherein the each cellular arrangement and the optical cross-talk mask (fig. 1, #180) are arranged orthogonal to a central axis of x-ray (col. 1, line 15) incidence on the cellular arrangement of

scintillators (fig. 1, #112) such that the optical cross-talk mask (fig. 1, #180) is sandwiched

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between the cellular arrangement of scintillators (fig. 1, #112) and the cellular arrangement of

photodiodes (fig. 1, #124).

12. Regarding claim 21, Possin et al. further discloses wherein the optical cross-talk mask

includes a cellular arrangement of mask elements (fig. 1, #180).

Regarding claim 22, Possin et al. further discloses wherein the step of providing an 13.

optical cross-talk mask (fig. 1, #180) includes the step of forming a grid of light-absorbing

elements (col. 5, lines 26-28).

Regarding claims 14 and 24, Possin et al. further discloses wherein the at least one mask 14.

is fabricated of at least black polyamide (col. 5, lines 32-40).

15. Regarding claim 25, Possin et al. further discloses wherein the optical cross-talk mask

(fig. 1, #180) is constructed to reduce cross-talk (title) between a scintillator (fig. 1, #112) and a

neighboring photodiode (fig. 1, #124).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all

obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are

such that the subject matter as a whole would have been obvious at the time the invention was made to a person

having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 6 and 23 are rejected under 35 U.S.C. 103(a) as being unpatentable over Possin et 16. al. as applied to claims 1 and 20 above, and further in view of Mattson et al. (US Patent 6553092).

Possin et al. discloses an apparatus as recited above.

However, Possin et al. fails to disclose reflecting material.

Mattson et al. teaches reflecting material (col. 4, lines 62-67).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to incorporate the apparatus of Possin et al. with the reflecting material of Mattson et al. based on the following reasoning. Since reflecting and absorbing materials were art-recognized equivalents at the time the invention was made for reducing cross-talk (col. 4, lines 62-67), one having ordinary skill in the art would have found it obvious to substitute one type of material for another. One would be motivated to make such a modification for reducing cross-talk (col.4, lines 59-67) as shown by Mattson et al. and based on what is readily available.

Claims 15 and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Mattson 17. et al. in view of Possin et al.

Mattson et al. discloses an apparatus comprising a rotatable gantry (fig. 1, #10) having a bore centrally disposed therein (fig. 1, #14), a table movable fore and aft (fig. 1, #12) through the bore (fig. 1, #14) and configured to position a subject for CT data acquisition (fig. 1, #20 and 30), a high frequency electromagnetic energy projection source (fig. 1, #16) positioned within the rotatable gantry (fig. 1, #10) and configured to project high frequency electromagnetic Application/Control Number: 10/707,407

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energy fan beam toward the subject (fig. 1, subject to be placed on #12), and a detector array (fig. 1, #20) disposed within the rotatable gantry (fig. 1, #10) and configured to detect high frequency electromagnetic energy projected by the projection source (fig. 1, #16) and impinged by the subject (fig. 1, subject to be placed on #12).

However, Mattson et al. does not disclose an array of scintillators, an array of photodiodes, and an array of optical cross-talk inhibitors formed of optically absorbent material and interstitially layered between the array of scintillators and the array of photodiodes, wherein the array of optical cross-talk inhibitors is fabricated from opaque materials.

Possin et al. teaches an array of scintillators (fig. 1, #112), an array of photodiodes (fig. 1, #124), and an array of optical cross-talk inhibitors (fig. 1, #180) formed of optically absorbent material (col. 5, lines 26-28) and interstitially layered between the array of scintillators (fig. 1, #112) and the array of photodiodes (fig. 1, #124), wherein the array of optical cross-talk inhibitors is fabricated from opaque materials (col. 5, lines 32-40).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to incorporate the apparatus of Mattson et al. as modified above detector of Possin et al., since one would be motivated to make such a modification for improving photosensor linearity and reducing crosstalk (title) as shown by Possin et al.

18. Claim 18 is rejected under 35 U.S.C. 103(a) as being unpatentable over Mattson et al. and Possin et al. as applied to claim 15 above, and further in view of Rushbrooke et al. (US Patent 5682411).

Mattson et al. as modified above suggests an apparatus as recited above.

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However, Mattson et al. does not disclose silicon.

Rushbrooke et al. teaches silicon (col. 2, lines 12-17).

It would have been obvious, to one having ordinary skill in the art at the time the invention was made, to incorporate the apparatus of Mattson et al. as modified above with the silicon of Rushbrooke et al., since it would have been within the general skill of a worker in the art to select a known material on the basis of its suitability. One would be motivated to make such a modification to reduce crosstalk (col. 2, lines 15-17) as implied from Rushbrooke et al.

## Response to Arguments

19. Applicant's arguments with respect to claims 1-9, 12-15, and 18-25 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event,

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however, will the statutory period for reply expire later than SIX MONTHS from the date of this

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final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Chih-Cheng Glen Kao whose telephone number is (571) 272-

2492. The examiner can normally be reached on M - F (9 am to 5 pm).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Ed Glick can be reached on (571) 272-2490. The fax phone number for the

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

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